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Understanding [Embedded - CPLDs \(Complex Programmable Logic Devices\)](#)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

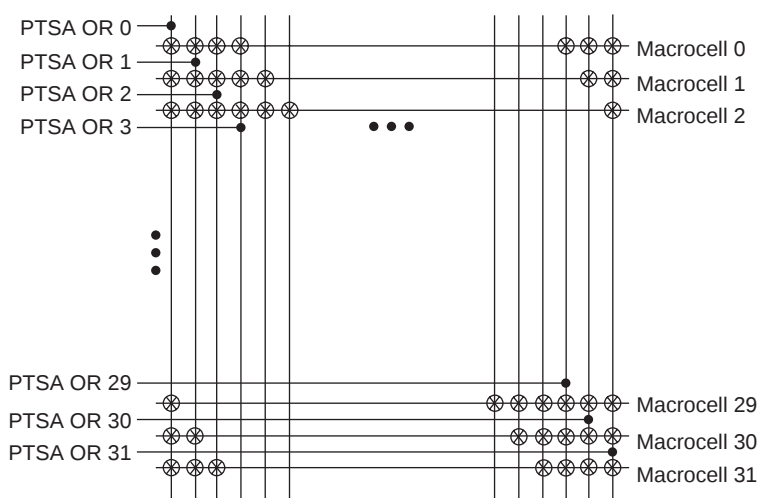
Details

Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	12 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	32
Number of Macrocells	1024
Number of Gates	-
Number of I/O	304
Operating Temperature	-40°C ~ 105°C (Tj)
Mounting Type	Surface Mount
Package / Case	484-BBGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lc51024vg-12f484i

Product Term Sharing Array

The Product Term Sharing Array (PTSA) consists of 32 inputs from the Dual-OR Array (Expandable PTSA OR) and 32 outputs directly to the macrocells. Each output is the OR term of any combination of the seven Expandable PTSA OR terms connected to that output. Every Nth macrocell is connected to N-3, N-2, N-1, N, N+1, N+2 and N+3 PTSA OR terms via a programmable connection. This wraps around the logic, Macrocell 0 gets its logic from 29, 30, 31, 0, 1, 2, 3. The Expandable PTSA OR used in conjunction with the PTSA allows wide functions to be implemented easily and efficiently. Without using the Expandable PTSA OR capability, the greatest number of product terms that can be included in a single function with one pass of delay is 35. Figure 6 shows the graphical representation of the PTSA.

Figure 6. Product Term Sharing Array

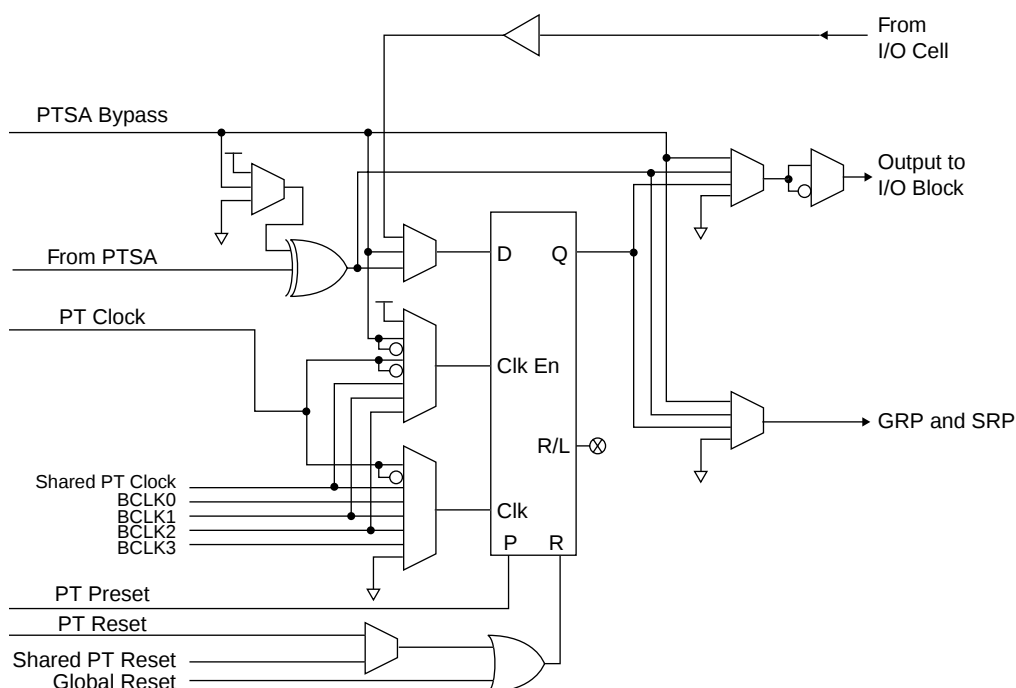


Macrocell

The 32 registered macrocells in the GLB are driven by the 32 outputs from the PTSA or the PTSA bypass. Each macrocell contains a programmable XOR gate, a programmable register/latch flip-flop and the necessary clocks and control logic to allow combinatorial or registered operation.

The macrocells each have two outputs, which can be fed to the SRP, GRP and I/O cell. This dual or concurrent output capability from the macrocell gives efficient use of the hardware resources. One output can be a registered function for example, while the other output can be an unrelated combinatorial function. A direct register input from the I/O cell facilitates efficient use of the macrocell to construct high-speed input registers.

Macrocell registers can be clocked from one of several global or product term clocks available on the device. A global and product term clock enable is also provided, eliminating the need to gate the clock to the macrocell registers directly. Reset and preset for the macrocell register is provided from both global and product term signals. The macrocell register can be programmed to operate as a D-type register or a D-type latch. Figure 7 is a graphical representation of the ispMACH 5000VG macrocell.

Figure 7. Macrocell

I/O Cell

The I/O cell of the ispMACH 5000VG device provides a high degree of flexibility. It includes the sysIO feature and an enhanced output enable MUX for optimal performance both on- and off-chip. The sysIO feature allows I/O cells to be configured to different I/O standards, drive strengths and slew rates. The enhanced output enable MUX provides up to 14 different output enable choices per I/O cell.

The I/O cell contains an output enable (OE) MUX, a programmable tri-state output buffer, a programmable input buffer, a programmable pull-up resistor, a programmable pull-down resistor and a programmable bus-keeper latch. The I/O cell receives its input from its associated macrocell. The I/O cell has a feedback line to its associated macrocell and a direct path to the GRP and SRP.

The output enable (OE) MUX selects the OE signal per I/O cell. The inputs to the OE MUX are the four Shared PTOE signals, PTOE and the two GOE signals. The OE MUX also has the ability to choose either the true or inverse of each of these signals. The output of the OE MUX goes through a logical AND with the TOE signal to allow easy tri-stating of the outputs for testing purposes.

The four shared PTOE signals are derived from PT163 of each GLB in the segment. The PTOE signal is derived from the first product term in each macrocell cluster, which is directly routed to the OE MUX. Therefore, every I/O cell can have a different OE signal. Figure 8 is a graphical representation of the I/O cell.

DC Electrical Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min	Typ	Max	Units
I _{IL} , I _{IH} ¹	Input or I/O Leakage Current	0V ≤ V _{IN} ≤ V _{IH} (MAX)	—	—	+/-10	μA
I _{PU} ²	I/O Weak Pull-up Resistor Current	V _{CCO} = 3.3	-30	—	-150	μA
		V _{CCO} = 2.5	-20	—	-150	μA
		V _{CCO} = 1.8	-10	—	-150	μA
I _{PD} ²	I/O Weak Pull-down Resistor Current	V _{IL} (MAX) ≤ V _{IN} ≤ V _{IH} (MAX)	30	—	150	μA
I _{BHLS} ²	Bus Hold Low Sustaining Current	V _{IN} = V _{IL} (MAX)	30	—	—	μA
I _{BHHS} ²	Bus Hold High Sustaining Current	V _{CCO} = 3.3	-30	—	—	μA
		V _{CCO} = 2.5	-20	—	—	μA
		V _{CCO} = 1.8	-10	—	—	μA
I _{BHLO} ²	Bus Hold Low Overdrive Current	0V ≤ V _{IN} ≤ V _{IH} (MAX)	—	—	150	μA
I _{BHHO} ²	Bus Hold High Overdrive Current	0V ≤ V _{IN} ≤ V _{IH} (MAX)	—	—	-150	μA
I _{CC} ^{3, 4, 5}	Operating Power Supply Current	V _{CC} = 3.3V	—	380	—	mA
V _{BHT}	Bus Hold Trip Points		V _{IL} (MAX)	—	V _{IH} (MIN)	V
C ₁	I/O Capacitance ³	V _{CC} = 3.3V, V _{IO} = 0 to V _{IH} (MAX)	—	10	—	pF
		V _{CCO} = 3.3V, 2.5, 1.8, 1.5				
C ₂	Clock Capacitance ³	V _{CC} = 3.3V, V _{IO} = 0 to V _{IH} (MAX)	—	10	—	pF
		V _{CCO} = 3.3V, 2.5, 1.8, 1.5				
C ₃	Global Input Capacitance ³	V _{CC} = 3.3V, V _{IO} = 0 to V _{IH} (MAX)	—	10	—	pF
		V _{CCO} = 3.3V, 2.5, 1.8, 1.5				

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tri-stated. It is not measured with the output driver active. Bus maintenance circuits are disabled.

2. Only available for LVCMOS and LVTTL standards.

3. $T_A = 25^\circ C$, $f = 1.0MHz$.

4. Device configured with 16-bit counters.

5. I_{CC} varies with specific device configuration and operating frequency.

sysIO DC Electrical Characteristics

Over Recommended Operating Conditions

Standard	V_{IL}		V_{IH}		V_{OL} Max (V)	V_{OH} Min (V)	I_{OL}^2 (mA)	I_{OH}^2 (mA)
	Min (V)	Max (V)	Min (V)	Max (V)				
LVCMOS 3.3 ¹	-0.3	0.8	2.0	5.5	0.4	2.4	20	-20
LVCMOS 3.3	-0.3	0.8	2.0	5.5	0.4	2.4	16, 12, 8, 5.33, 4	-16, -12, -8, -5.33, -4
					0.2	$V_{CCO} - 0.2$	0.1	-0.1
LVTTTL	-0.3	0.8	2.0	5.5	0.4	2.4	20	-20
					0.2	$V_{CCO} - 0.2$	0.1	-0.1
LVCMOS 2.5	-0.3	0.7	1.7	3.6	0.4	$V_{CCO} - 0.4$	16, 12, 8, 5.33, 4	-16, -12, -8, -5.33, -4
					0.2	$V_{CCO} - 0.2$	0.1	-0.1
LVCMOS 1.8	-0.3	$0.35V_{CCO}$	$0.65V_{CCO}$	3.6	0.4	$V_{CCO} - 0.4$	12, 8, 5.33, 4	-12, -8, -5.33, -4
					0.2	$V_{CCO} - 0.2$	0.1	-0.1
PCI 3.3	-0.3	$0.3V_{CCO}$	$0.5V_{CCO}$	3.6	$0.1V_{CCO}$	$0.9V_{CCO}$	1.5	-0.5
PCI-X	-0.3	$0.35V_{CCO}$	$0.5V_{CCO}$	3.6	$0.1V_{CCO}$	$0.9V_{CCO}$	1.5	-0.5
AGP-1X	-0.3	$0.3V_{CCO}$	$0.5V_{CCO}$	3.6	$0.1V_{CCO}$	$0.9V_{CCO}$	1.5	-0.5
SSTL3 class I	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	0.7	$V_{CCO} - 1.1$	8	-8
SSTL3 class II	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	0.5	$V_{CCO} - 0.9$	16	-16
SSTL2 class I	-0.3	$V_{REF} - 0.18$	$V_{REF} + 0.18$	3.6	0.54	$V_{CCO} - 0.62$	7.6	-7.6
SSTL2 class II	-0.3	$V_{REF} - 0.18$	$V_{REF} + 0.18$	3.6	0.35	$V_{CCO} - 0.43$	15.2	-15.2
CTT 3.3	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	$V_{REF} - 0.4$	$V_{REF} + 0.4$	8	-8
CTT 2.5	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	$V_{REF} - 0.4$	$V_{REF} + 0.4$	8	-8
HSTL class I	-0.3	$V_{REF} - 0.1$	$V_{REF} + 0.1$	3.6	0.4	$V_{CCO} - 0.4$	8	-8
HSTL class III	-0.3	$V_{REF} - 0.1$	$V_{REF} + 0.1$	3.6	0.4	$V_{CCO} - 0.4$	24	-8
GTL+	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	0.6	n/a	36	n/a

1. Software default setting

2. The average DC current drawn by I/Os between adjacent bank GND connections, or between the last GND in an I/O bank and the end of the I/O bank, as shown in the logic signals connection table, shall not exceed 96mA.

sysIO Differential Input DC Electrical Characteristics and Operating Conditions

Symbol	Parameter	Test Conditions	Min	Max
$V_{INP} \cdot V_{INM}$	LVDS Input voltage	—	0	2.4
V_{THD}	LVDS Differential input threshold	—	$\pm 100\text{mV}$	—
V_{IL}	LVPECL Input Voltage Low	$V_{CC} = 3.0 \text{ to } 3.6\text{V}$	$V_{CC} - 1.81$	$V_{CC} - 1.48$
		$V_{CC} = 3.3\text{V}$	1.49V	1.83V
V_{IH}	LVPECL Input Voltage High	$V_{CC} = 3.0 \text{ to } 3.6\text{V}$	$V_{CC} - 1.17$	$V_{CC} - 0.88$
		$V_{CC} = 3.3\text{V}$	2.14V	2.42V

ispMACH 5768VG External Switching Characteristics

Over Recommended Operating Conditions

Parameter	Description ^{1,2,3}	-5		-75		-10		-12		Units
		Min	Max	Min	Max	Min	Max	Min	Max	
t_{PD}	Data propagation delay, 5-PT bypass	—	5.0	—	7.5	—	10.0	—	12.0	ns
t_{PD_PTSA}	Data propagation delay, intrasegment path	—	6.0	—	9.0	—	11.5	—	13.5	ns
t_{PD_GLOBAL}	Data propagation delay, intersegment path	—	6.5	—	9.75	—	13.0	—	16.0	ns
t_S	GLB register setup time before clock, 5-PT bypass	3.0	—	5.0	—	7.5	—	9.3	—	ns
t_{S_PTSA}	GLB register setup time before clock	3.0	—	6.0	—	8.5	—	10.0	—	ns
t_{SIR}	GLB register setup time before clock, input register path	2.8	—	3.0	—	4.0	—	5.0	—	ns
t_H	GLB register hold time before clock, 5-PT bypass	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{H_PTSA}	GLB register hold time before clock	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{HIR}	GLB register hold time before clock, input reg. path	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{CO}	GLB register clock-to-output delay	—	4.4	—	5.0	—	6.0	—	7.0	ns
t_R	External reset pin to output delay	—	6.5	—	9.0	—	10.0	—	10.9	ns
t_{RW}	External reset pulse duration	4.0	—	6.0	—	8.0	—	9.5	—	ns
$t_{LPTOE/DIS}$	Input to output local product term output enable/disable	—	7.0	—	9.75	—	11.5	—	13.4	ns
$t_{SPTOE/DIS}$	Input to output segment product term output enable/disable	—	8.0	—	11.25	—	17.5	—	20.4	ns
$t_{GOE/DIS}$	Global OE input to output enable/disable	—	6.2	—	7.5	—	8.85	—	10.0	ns
t_{CW}	Global clock width, high or low	1.6	—	2.75	—	3.6	—	4.3	—	ns
t_{GW}	Global gate width low (for low transparent) or high (for high transparent)	1.8	—	2.75	—	3.6	—	4.3	—	ns
t_{WIR}	Input register clock width, high or low	1.8	—	2.75	—	3.6	—	4.3	—	ns
t_{SKEW}	Clock-to-out skew, block level	—	0.25	—	0.35	—	0.45	—	0.55	ns
	Clock-to-out skew, segment level	—	0.4	—	0.5	—	0.6	—	0.7	ns
f_{MAX}^4	Clock frequency with internal feedback	178.6	—	117.0	—	87.0	—	73.0	—	MHz
$f_{MAX} (Ext.)$	Clock frequency with external feedback, $1/(t_{S_PTSA} + t_{CO})$	135.1	—	90.9	—	69.0	—	58.8	—	MHz
$f_{MAX} (Tog.)$	Clock frequency max Toggle	312.5	—	181.0	—	138.0	—	116.0	—	MHz

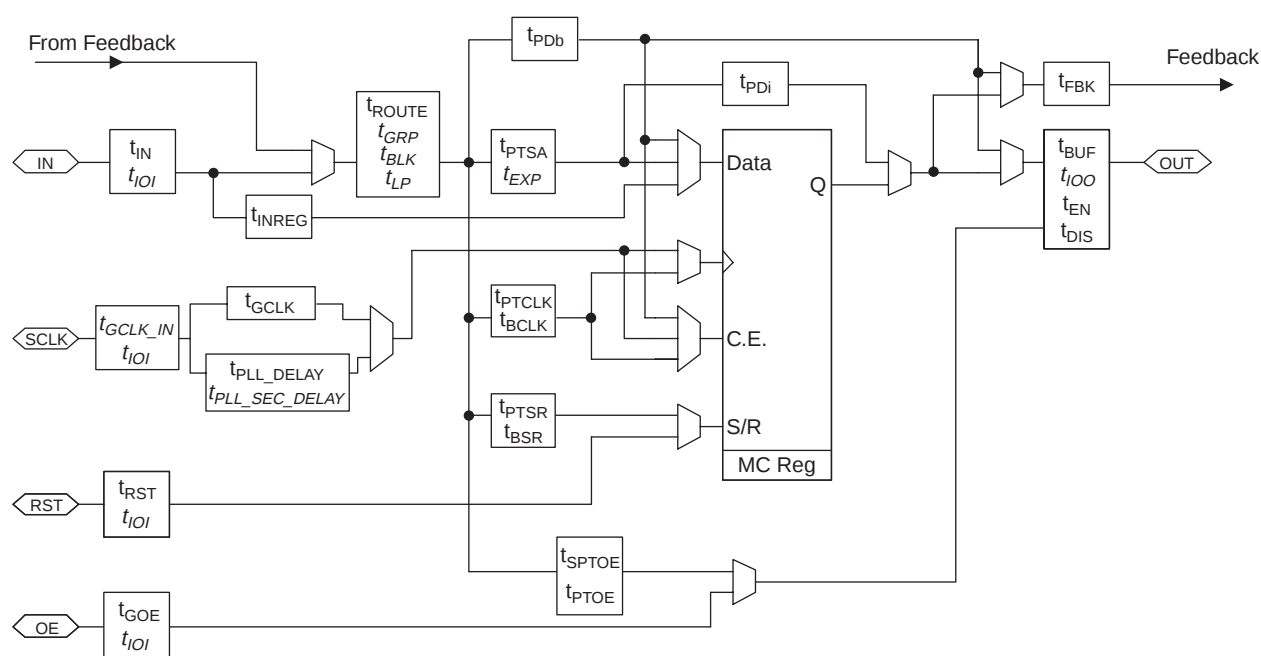
Timing v.1.20

1. Timing numbers are based on default LVCMOS 3.3 I/O Buffers. Use timing adjusters provided to calculate timing for other standards.
2. Measured using standard switching circuit, assuming segment and global routing loading of 1, worst case PTSA loading and 1 output switching.
3. Pulse widths and clock widths less than minimum will cause unknown behavior.
4. Standard 16-bit counter using SRP feedback.

Timing Model

The task of determining the timing through the ispMACH 5000VG family, like any CPLD, is relatively simple. The timing model provided in Figure 11 shows the specific delay paths. Once the implementation of a given function is determined either conceptually or from the software report file, the delay path of the function can easily be determined from the timing model. The Lattice design tools report the timing delays based on the same timing model for a particular design. Note that the internal timing parameters are given for reference only, and are not tested. The external timing parameters are tested and guaranteed for every device. For more information on the timing model and usage, please refer to Technical Note TN1001: *ispMACH 5000VG Timing Model Design and Usage Guidelines*.

Figure 11. ispMACH 5000VG Timing Model



Italicized items are optional delay adders

ispMACH 5768VG Internal Timing Parameters

Over Recommended Operating Conditions

Parameter	Description	-5		-75		-10		-12		Units
		Min	Max	Min	Max	Min	Max	Min	Max	
In/Out Delays										
t _{IN}	Input Buffer Delay	—	0.65	—	0.95	—	1.25	—	1.40	ns
t _{GCLK_IN}	Global Clock Input Buffer Delay	—	0.65	—	0.95	—	1.25	—	1.40	ns
t _{GOE}	Global OE Pin Delay	—	4.05	—	5.00	—	6.00	—	7.00	ns
t _{BUF}	Delay through Output Buffer	—	1.15	—	1.50	—	1.75	—	1.90	ns
t _{EN}	Output Enable Time	—	2.15	—	2.50	—	2.85	—	3.00	ns
t _{DIS}	Output Disable Time	—	2.15	—	2.50	—	2.85	—	3.00	ns
t _{RSTb}	Global RESETbar Pin Delay	—	4.60	—	6.50	—	7.00	—	7.50	ns
Routing Delays										
t _{ROUTE}	Delay through SRP	—	2.80	—	4.20	—	5.65	—	6.90	ns
t _{PTSA}	Product Term Sharing Array Delay	—	0.40	—	1.85	—	2.35	—	2.50	ns
t _{PDB}	5-PT Bypass Propagation Delay	—	0.40	—	0.85	—	1.35	—	1.80	ns
t _{PDi}	Macrocell Propagation Delay	—	1.00	—	0.50	—	0.50	—	0.80	ns
t _{INREG}	Input Buffer to Macrocell Register Delay	—	3.00	—	3.05	—	3.50	—	4.40	ns
t _{FBK}	Internal Feedback Delay	—	0.00	—	0.00	—	0.00	—	0.00	ns
t _{GCLK}	Global Clock Tree Delay	—	0.85	—	0.70	—	0.55	—	0.65	ns
t _{PLL_DELAY}	Programmable PLL Delay Increment	—	0.50	—	0.50	—	0.50	—	0.50	ns
t _{PLL_SEC_DELAY}	Additional Delay When Using Secondary PLL Output	—	0.60	—	0.60	—	0.60	—	0.60	ns
t _{GRP}	Global Routing Pool Delay	—	1.50	—	2.25	—	3.00	—	4.00	ns
Register/Latch Delays										
t _S	D-Register Setup Time	0.65	—	0.65	—	1.05	—	1.25	—	ns
t _{S_PT}	D-Register Setup Time with PT Clock	0.65	—	0.65	—	1.05	—	1.25	—	ns
t _H	D-Register Hold Time	0.00	—	0.00	—	0.00	—	0.00	—	ns
t _{ST}	T-Register Setup Time	1.15	—	1.15	—	1.55	—	1.75	—	ns
t _{ST_PT}	T-Register Setup Time with PT Clock	1.15	—	1.15	—	1.55	—	1.75	—	ns
t _{HT}	T-Register Hold Time	0.00	—	0.00	—	0.00	—	0.00	—	ns
t _{COi}	Register Clock to Output/Feedback MUX Time	—	1.75	—	1.85	—	2.45	—	3.05	ns
t _{CES}	Clock Enable Setup Time	2.60	—	3.90	—	5.05	—	5.95	—	ns
t _{CEH}	Clock Enable Hold Time	0.60	—	0.90	—	1.20	—	1.45	—	ns
t _{SL}	Latch Setup Time	2.80	—	4.20	—	5.50	—	6.60	—	ns
t _{SL_PT}	Latch Setup Time with PT Clock	2.80	—	4.20	—	5.50	—	6.60	—	ns
t _{HL}	Latch Hold Time	0.00	—	0.00	—	0.00	—	0.00	—	ns
t _{GOi}	Latch Gate to Output/Feedback MUX Time	—	1.75	—	2.50	—	3.50	—	4.50	ns
t _{PDLi}	Propagation Delay through Transparent Latch to Output/Feedback MUX	—	2.40	—	3.50	—	4.00	—	4.50	ns
t _{SRI}	Asynchronous Reset or Set to Output/Feedback MUX Delay	—	0.75	—	1.00	—	1.25	—	1.50	ns
t _{SRR}	Asynchronous Reset or Set Recovery Delay	—	1.00	—	1.50	—	2.00	—	2.50	ns
Control Delays										
t _{BCLK}	GLB PT Clock Delay	—	3.10	—	4.65	—	6.00	—	7.00	ns
t _{PTCLK}	Macrocell PT Clock Delay	—	3.00	—	4.50	—	6.00	—	7.00	ns

ispMACH 51024VG Internal Timing Parameters (Continued)

Over Recommended Operating Conditions

Parameter	Description	-5		-75		-10		-12		Units
		Min	Max	Min	Max	Min	Max	Min	Max	
t_{CES}	Clock Enable Setup Time	2.60	—	3.90	—	5.05	—	5.95	—	ns
t_{CEH}	Clock Enable Hold Time	0.60	—	0.90	—	1.20	—	1.45	—	ns
t_{SL}	Latch Setup Time	2.80	—	4.20	—	5.50	—	6.60	—	ns
t_{SL_PT}	Latch Setup Time with PT Clock	2.80	—	4.20	—	5.50	—	6.60	—	ns
t_{HL}	Latch Hold Time	0.00	—	0.00	—	0.00	—	0.00	—	ns
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	1.75	—	2.50	—	3.50	—	4.50	ns
t_{PDLi}	Propagation Delay through Transparent Latch to Output/Feedback MUX	—	2.40	—	3.50	—	4.00	—	4.50	ns
t_{SRi}	Asynchronous Reset or Set to Output/Feedback MUX Delay	—	0.75	—	1.00	—	1.25	—	1.50	ns
t_{SRR}	Asynchronous Reset or Set Recovery Delay	—	1.00	—	1.50	—	2.00	—	2.50	ns
Control Delays										
t_{BCLK}	GLB PT Clock Delay	—	3.10	—	4.65	—	6.00	—	7.00	ns
t_{PTCLK}	Macrocell PT Clock Delay	—	3.00	—	4.50	—	6.00	—	7.00	ns
t_{BSR}	Block PT Set/Reset Delay	—	2.00	—	3.00	—	4.00	—	4.80	ns
t_{PTSR}	Macrocell PT Set/Reset Delay	—	2.00	—	3.00	—	4.00	—	4.80	ns
t_{SPTOE}	Segment PT OE Delay	—	2.40	—	3.60	—	7.75	—	9.10	ns
t_{PTOE}	Macrocell PT OE Delay	—	1.40	—	2.10	—	1.75	—	2.10	ns

Notes:

Timing v.1.1.10

1. Internal Timing Parameters are not tested and are for reference only. Refer to Timing Model in this data sheet for further details.
2. t_{PLL_DELAY} is the unit increment by which the clock signal can be incremented. The PLL can adjust the clock signal by up to 3.5ns in either direction in units of 0.5ns for each step.

ispMACH 5768VG Timing Adders (Continued)

Adder Type	Base Parameter	Description	-5		-75		-10		-12		Units
			Min	Max	Min	Max	Min	Max	Min	Max	
LVC MOS18_12mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 1.8V & 12mA Buffer	—	1.35	—	1.35	—	1.35	—	1.35	ns
LVC MOS25_4mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 2.5V & 4mA Buffer	—	1.50	—	1.50	—	1.50	—	1.50	ns
LVC MOS25_5mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 2.5V & 5.33mA Buffer	—	1.25	—	1.25	—	1.25	—	1.25	ns
LVC MOS25_8mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 2.5V & 8mA Buffer	—	0.70	—	0.70	—	0.70	—	0.70	ns
LVC MOS25_12mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 2.5V & 12mA Buffer	—	0.50	—	0.50	—	0.50	—	0.50	ns
LVC MOS25_16mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 2.5V & 16mA Buffer	—	0.25	—	0.25	—	0.25	—	0.25	ns
LVC MOS33_4mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 3.3V & 4mA Buffer	—	1.50	—	1.50	—	1.50	—	1.50	ns
LVC MOS33_5mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 3.3V & 5.33mA Buffer	—	1.25	—	1.25	—	1.25	—	1.25	ns
LVC MOS33_8mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 3.3V & 8mA Buffer	—	0.40	—	0.40	—	0.40	—	0.40	ns
LVC MOS33_12mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 3.3V & 12mA Buffer	—	0.10	—	0.10	—	0.10	—	0.10	ns
LVC MOS33_16mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 3.3V & 16mA Buffer	—	0.0	—	0.0	—	0.0	—	0.0	ns
LVC MOS33_20mA_out	t_{BUF} , t_{EN} , t_{DIS}	Output configured as 3.3V & 20mA Buffer	—	0.0	—	0.0	—	0.0	—	0.0	ns
LVTTL	t_{BUF} , t_{EN} , t_{DIS}	Output configured as LVTTL Buffer	—	0.0	—	0.0	—	0.0	—	0.0	ns
Slow Slew	t_{BUF} , t_{EN}	Output configured for slow slew rate	—	1.50	—	1.50	—	1.50	—	1.50	ns
PCI_out	t_{BUF} , t_{EN} , t_{DIS}	Using PCI standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
PCI_X_out	t_{BUF} , t_{EN} , t_{DIS}	Using PCI-X standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
AGP_1X_out	t_{BUF} , t_{EN} , t_{DIS}	Using AGP-1X standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
SSTL3_I_out	t_{BUF} , t_{EN} , t_{DIS}	Using SSTL3_I standard	—	-0.25	—	-0.25	—	-0.25	—	-0.25	ns
SSTL3_II_out	t_{BUF} , t_{EN} , t_{DIS}	Using SSTL3_II standard	—	-0.35	—	-0.35	—	-0.35	—	-0.35	ns
SSTL2_I_out	t_{BUF} , t_{EN} , t_{DIS}	Using SSTL2_I standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
SSTL2_II_out	t_{BUF} , t_{EN} , t_{DIS}	Using SSTL2_II standard	—	-0.25	—	-0.25	—	-0.25	—	-0.25	ns
CTT33_out	t_{BUF} , t_{EN} , t_{DIS}	Using CCT3.3 standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
CTT25_out	t_{BUF} , t_{EN} , t_{DIS}	Using CCT2.5 standard	—	0.25	—	0.25	—	0.25	—	0.25	ns
HSTL_I_out	t_{BUF} , t_{EN} , t_{DIS}	Using HSTL_I standard	—	-0.30	—	-0.30	—	-0.30	—	-0.30	ns

Note: Open drain timing is the same as corresponding LVC MOS timing.

Timing v.1.20

ispMACH 5768VG Timing Adders (Continued)

Adder Type	Base Parameter	Description	-5		-75		-10		-12		Units
			Min	Max	Min	Max	Min	Max	Min	Max	
HSTL_III_out	t_{BUF} , t_{EN} , t_{DIS}	Using HSTL_III standard	—	0.00	—	0.00	—	0.00	—	0.00	ns
GTL+_out	t_{BUF} , t_{EN} , t_{DIS}	Using GTL+ standard	—	0.30	—	0.30	—	0.30	—	0.30	ns

Note: Open drain timing is the same as corresponding LVCMOS timing.

Timing v.1.20

ispMACH 51024VG Timing Adders

Adder Type	Base Parameter	Description	-5		-75		-10		-12		Units
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{BLA}	t_{ROUTE}	GLB Loading Adder	—	0.0	—	0.0	—	0.0	—	0.0	ns
t_{EXP}	t_{PTSA}	PT Expander Adder	—	1.5	—	2.0	—	2.5	—	2.5	ns
t_{LP}	t_{ROUTE}	Low Power Adder	—	1.5	—	1.5	—	1.5	—	1.5	ns
t_{OI} Input Adders											
LVCMOS18_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using LVCMOS1.8 standard	—	0.90	—	0.90	—	0.90	—	0.90	ns
LVCMOS25_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using LVCMOS2.5 standard	—	0.15	—	0.15	—	0.15	—	0.15	ns
LVCMOS33_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using LVCMOS3.3 standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
LVTTL	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using LVTTL standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
PCI_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using PCI standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
PCI_X_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using PCI_X standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
AGP_1X_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using AGP-1X standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
SSTL3_I_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using SSTL3_I standard	—	1.00	—	1.00	—	1.00	—	1.00	ns
SSTL3_II_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using SSTL3_II standard	—	1.00	—	1.00	—	1.00	—	1.00	ns
SSTL2_I_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using SSTL2_I standard	—	1.00	—	1.00	—	1.00	—	1.00	ns
SSTL2_II_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using SSTL2_II standard	—	1.00	—	1.00	—	1.00	—	1.00	ns
CTT33_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using CTT3.3 standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
CTT25_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using CTT2.5 standard	—	0.15	—	0.15	—	0.15	—	0.15	ns
HSTL_I_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using HSTL_I standard	—	1.25	—	1.25	—	1.25	—	1.25	ns
HSTL_III_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using HSTL_III standard	—	1.25	—	1.25	—	1.25	—	1.25	ns
GTL+_in	t_{IN} , t_{GCLK_IN} , t_{RSTb} , t_{GOE}	Using GTL+ standard	—	1.50	—	1.50	—	1.50	—	1.50	ns

Note: Open drain timing is the same as corresponding LVCMOS timing.

Timing v.1.10

ispMACH 51024VG Timing Adders (Continued)

Adder Type	Base Parameter	Description	-5		-75		-10		-12		Units
			Min	Max	Min	Max	Min	Max	Min	Max	
LVDS_in	t_{GCLK_IN}	Using LVDS standard	—	1.70	—	1.70	—	1.70	—	1.70	ns
LVPECL_in	t_{GCLK_IN}	Using LVPECL standard	—	2.10	—	2.10	—	2.10	—	2.10	ns
t_{IOO} Output Adders											
LVC MOS18_4mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 1.8V & 4mA Buffer	—	3.00	—	3.00	—	3.00	—	3.00	ns
LVC MOS18_5mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 1.8V & 5.33mA Buffer	—	2.50	—	2.50	—	2.50	—	2.50	ns
LVC MOS18_8mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 1.8V & 8mA Buffer	—	1.85	—	1.85	—	1.85	—	1.85	ns
LVC MOS18_12mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 1.8V & 12mA Buffer	—	1.35	—	1.35	—	1.35	—	1.35	ns
LVC MOS25_4mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 2.5V & 4mA Buffer	—	1.50	—	1.50	—	1.50	—	1.50	ns
LVC MOS25_5mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 2.5V & 5.33mA Buffer	—	1.25	—	1.25	—	1.25	—	1.25	ns
LVC MOS25_8mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 2.5V & 8mA Buffer	—	0.70	—	0.70	—	0.70	—	0.70	ns
LVC MOS25_12mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 2.5V & 12mA Buffer	—	0.50	—	0.50	—	0.50	—	0.50	ns
LVC MOS25_16mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 2.5V & 16mA Buffer	—	0.25	—	0.25	—	0.25	—	0.25	ns
LVC MOS33_4mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 3.3V & 4mA Buffer	—	1.50	—	1.50	—	1.50	—	1.50	ns
LVC MOS33_5mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 3.3V & 5.33mA Buffer	—	1.25	—	1.25	—	1.25	—	1.25	ns
LVC MOS33_8mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 3.3V & 8mA Buffer	—	0.40	—	0.40	—	0.40	—	0.40	ns
LVC MOS33_12mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 3.3V & 12mA Buffer	—	0.10	—	0.10	—	0.10	—	0.10	ns
LVC MOS33_16mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 3.3V & 16mA Buffer	—	0.0	—	0.0	—	0.0	—	0.0	ns
LVC MOS33_20mA_out	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as 3.3V & 20mA Buffer	—	0.0	—	0.0	—	0.0	—	0.0	ns
LVTTL	$t_{BUF} t_{EN}, t_{DIS}$	Output configured as LVTTL Buffer	—	0.0	—	0.0	—	0.0	—	0.0	ns
Slow Slew	$t_{BUF} t_{EN}$	Output configured for slow slew rate	—	1.50	—	1.50	—	1.50	—	1.50	ns
PCI_out	$t_{BUF} t_{EN}, t_{DIS}$	Using PCI standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
PCI_X_out	$t_{BUF} t_{EN}, t_{DIS}$	Using PCI-X standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
AGP_1X_out	$t_{BUF} t_{EN}, t_{DIS}$	Using AGP-1X standard	—	0.0	—	0.0	—	0.0	—	0.0	ns
SSTL3_I_out	$t_{BUF} t_{EN}, t_{DIS}$	Using SSTL3_I standard	—	-0.25	—	-0.25	—	-0.25	—	-0.25	ns
SSTL3_II_out	$t_{BUF} t_{EN}, t_{DIS}$	Using SSTL3_II standard	—	-0.35	—	-0.35	—	-0.35	—	-0.35	ns

Note: Open drain timing is the same as corresponding LVC MOS timing.

Timing v.1.10

sysCLOCK PLL Timing

Over Recommended Operating Conditions¹

Symbol	Parameter	Conditions	Min	Max	Units
t_R, t_F	Input clock, rise and fall time	20% to 80%	—	3.0	ns
t_{INSTB}	Input clock stability, period jitter (peak) ¹	—	—	+/- 200	ps
t_{PWH}	Input clock, high time	—	1.6	—	ns
t_{PWL}	Input clock, low time	—	1.6	—	ns
f_{MDIVIN}	M Divider input, frequency range	—	5	180	MHz
$f_{MDIVOUT}$	M Divider output, frequency range	—	5	180	MHz
f_{VDIVIN}	V Divider input, frequency range	—	60	200	MHz
$f_{VDIVOUT}$	V Divider output, frequency range	—	5	180	MHz
$t_{OUTDUTY}$	Output clock, duty cycle	—	40	60	%
$t_{JIT(CC)}$	Output clock, cycle to cycle jitter (peak)	Clean Reference, $5\text{MHz} \leq f_{MDIVOUT} < 80\text{MHz}$	—	+/- 200	ps
		Clean Reference, $80\text{MHz} \leq f_{MDIVOUT} \leq 180\text{MHz}$	—	+/- 100	ps
$t_{JIT(\phi)}$	Output clock, accumulated phase jitter (peak) ²	Clean Reference, $5\text{MHz} \leq f_{MDIVOUT} < 80\text{MHz}$	—	+/- 200	ps
		Clean Reference, $80\text{MHz} \leq f_{MDIVOUT} \leq 180\text{MHz}$	—	+/- 100	ps
$t_{CLK_OUT_DLY}$	Input clock to CLK_OUT delay	Internal feedback	—	1	ns
t_ϕ	Input clock to external feedback delta	External feedback	—	500	ps
t_{LOCK}	Time to acquire phase lock after input stable	—	—	30	μs
t_{PLL_DELAY}	Delay increment	—	+/- 0.35	+/- 0.65	ns
t_{RANGE}	Total output delay range	—	+/- 2.45	+/- 4.55	ns
t_{PLL_RSTR}	Reset recovery time of the M-divider	—	11.0	—	ns
t_{PLL_RSTW}	Minimum reset pulse width	—	6.0	—	ns

1. This condition assures that the output phase jitter ($t_{JIT(\phi)}$) will remain within specification.

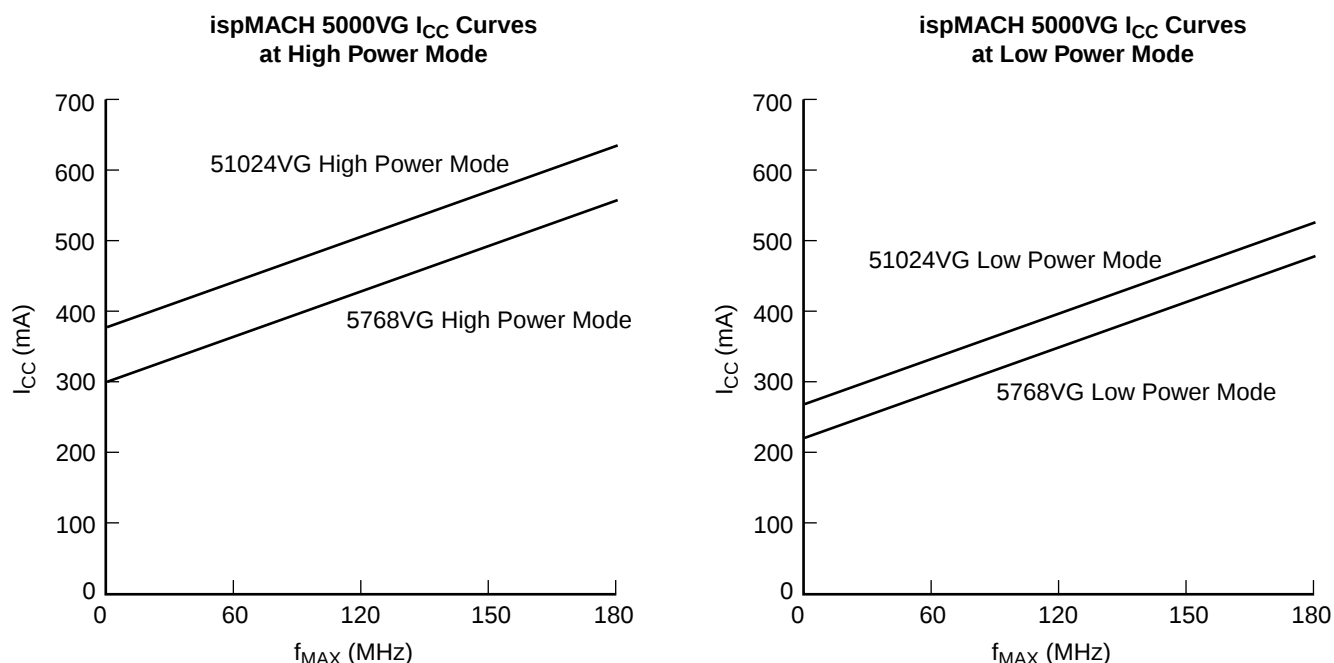
2. Accumulated jitter measured over 10,000 waveform samples.

Boundary Scan Timing Specifications

Symbol	Parameter	Min.	Max.	Units
t_{BTCP}	TCK [BSCAN test] clock cycle	40	—	ns
t_{BTCH}	TCK [BSCAN test] pulse width high	20	—	ns
t_{BTCL}	TCK [BSCAN test] pulse width low	20	—	ns
t_{BTSU}	TCK [BSCAN test] setup time	8	—	ns
t_{BTH}	TCK [BSCAN test] hold time	10	—	ns
t_{BRF}	TCK [BSCAN test] rise and fall time	50	—	mV/ns
t_{BTCO}	TAP controller falling edge of clock to valid output	—	10	ns
t_{BTOZ}	TAP controller falling edge of clock to data output disable	—	10	ns
t_{BTVO}	TAP controller falling edge of clock to data output enable	—	10	ns
$t_{BVTCPUSU}$	BSCAN test Capture register setup time	8	—	ns
t_{BTCPH}	BSCAN test Capture register hold time	10	—	ns
t_{BTUCO}	BSCAN test Update reg, falling edge of clock to valid output	—	25	ns
t_{BTUOZ}	BSCAN test Update reg, falling edge of clock to output disable	—	25	ns
t_{BTUOV}	BSCAN test Update reg, falling edge of clock to output enable	—	25	ns

Power Consumption

ispMACH 5000VG Typical Power vs. Frequency



Note: The devices are configured with maximum number of 16-bit counters, no PLL, typical current at 3.3V, 25° C.

Power Estimation Coefficients

Device	K0	K1	K2	K3	K4	K5	K6	I_{DC} (mA)	I_{DCO} (mA)
ispMACH 5768VG	0.0014	0.0014	0.054	1.5	0.152	0.105	5.0	65	20
ispMACH 51024VG	0.0014	0.0014	0.054	1.5	0.152	0.105	5.0	80	20

Note: For further information about the use of these coefficients, refer to Technical Note TN1002, *Power Estimation in ispMACH 5000VG Devices*.

K0 = average current per product term in high power/MHz

K1 = average current per product term in low power/MHz

K2 = average current per GRP line/MHz

K3 = average current per PLL/MHz

K4 = DC current per product terms in high power

K5 = DC current per product terms in low power

K6 = Static DC current per PLL

I_{DC} = Static device current with all product terms powered off

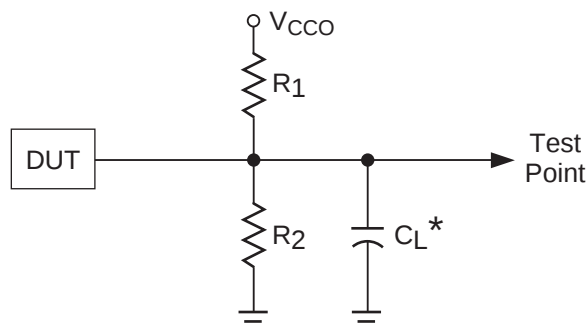
I_{DCO} = Static I/O bank current

I_{CC} estimates are based on typical conditions ($V_{CC} = 3.3V$, room temperature) and an assumption of one GLB load on average exists. These values are for estimates only. Since the value of I_{CC} is sensitive to operating conditions and the program in the device, the actual I_{CC} should be verified.

Switching Test Conditions

Figure 12 shows the output test load that is used for AC testing. The specific values for resistance, capacitance, voltage, and other test conditions are shown in Table 3.

Figure 12. Output Test Load, LVTTTL and LVCMOS Standards



* C_L includes Test Fixture and Probe Capacitance.

0213A/ispM5kvg

Table 3. Test Fixture Required Components

Test Condition	R_1	R_2	C_L	Timing Ref.	V_{CCO}
Default LVCMOS 3.3 I/O (L -> H, H -> L)	110	110	35pF	1.5	3.0V
Other LVCMOS Settings, (L -> H, H -> L)	∞	∞	35pF	LVCMOS 3.3 = 1.5V	LVCMOS 3.3 = 3.0V
				LVCMOS 2.5 = $V_{CCO}/2$	LVCMOS 2.5 = 2.3V
				LVCMOS 1.8 = $V_{CCO}/2$	LVCMOS 1.8 = 1.65V
Default LVCMOS 3.3 I/O (Z -> H)	∞	110	35pF	1.5V	3.0V
Default LVCMOS 3.3 I/O (Z -> L)	110	∞	35pF	1.5V	3.0V
Default LVCMOS 3.3 I/O (H -> Z)	∞	110	5pF	$V_{OH} - 0.3$	3.0V
Default LVCMOS 3.3 I/O (L -> Z)	110	∞	5pF	$V_{OL} + 0.3$	3.0V

Output test conditions for all other interfaces are determined by the respective standards. For further details, please refer to the following technical note:

- *ispMACH 5000VG sysIO Design and Usage Guidelines (TN1000)*

ispMACH 5768VG Logic Signal Connections

Bank No.	Signal	256 fpBGA	484 fpBGA
0	0C-30	C8	D11
0	0C-28	B6	B11
0	0C-26	A5	E12
0	0C-24	D8	C11
0	0C-22	E8	F12
0	0C-20	B5	B10
0	GNDIO0	GND	GND
0	0C-18	A4	A10
0	0C-16	D7	D10
0	0C-14/VREF0	E7	A9
0	0C-12	C6	E11
0	0C-10	B4	B9
0	0C-8	A3	F11
0	0C-6	NC	A8
0	0C-4	NC	C10
0	0C-2	NC	A7
0	0C-0	NC	E10
0	0D-30	NC	B8
0	0D-28	NC	C8
0	GNDIO0	GND	GND
0	0D-26	NC	F10
0	0D-24	NC	A6
0	0D-22	NC	F9
0	0D-20	NC	C7
0	0D-18	NC	D9
0	0D-16	NC	B7
0	0D-14	D6	E8
0	0D-12	E6	A5
0	0D-10	A2	F8
0	0D-8	B3	C6
0	0D-6	C4	D8
0	0D-4	D5	A3
0	GNDIO0	GND	GND
0	0D-2	NC	A2
0	0D-0	NC	A4
0	0A-0	NC	F7
0	0A-2	NC	C5
0	0A-4	NC	F6
0	0A-6	NC	B3
0	0A-8	NC	NC
0	0A-10	NC	NC
0	GNDIO0	GND	GND
0	0A-12	NC	NC

Bank No.	Signal	256 fpBGA	484 fpBGA
0	0A-14	NC	NC
0	0A-16	NC	B4
0	0A-18	NC	D5
0	0A-20	NC	B1
0	0A-22	NC	D6
0	0A-24	NC	C4
0	0A-26	NC	E4
0	GNDIO0	GND	GND
0	0A-28	B2	C2
0	0A-30	B1	C1
0	0B-30	C2	D1
0	0B-28	C1	D2
0	0B-26	NC	D3
0	0B-24	NC	E1
0	0B-22	NC	E3
0	0B-20	NC	F4
0	0B-18	NC	F1
0	0B-16	NC	F3
0	0B-14	NC	G6
0	0B-12	NC	G1
0	GNDIO0	GND	GND
0	0B-10	NC	G2
0	0B-8	NC	H1
0	0B-6	NC	G3
0	0B-4	NC	H2
0	0B-2	NC	H5
0	0B-0	NC	H6
0	1A-0	F7	J1
0	1A-2	F6	K1
0	1A-4	E5	H3
0	1A-6	D4	J2
0	1A-8	D3	H4
0	1A-10	D2	K2
0	GNDIO0	GND	GND
0	1A-12	D1	J6
0	1A-14	E4	L1
0	1A-16	NC	K3
0	1A-18	NC	J4
0	1A-20	NC	L2
0	1A-22	NC	M1
0	1A-24	NC	K6
0	1A-26	NC	K4
0	1A-28	NC	L3

ispMACH 5768VG Logic Signal Connections (Continued)

Bank No.	Signal	256 fpBGA	484 fpBGA
3	4B-24	G11	M19
3	4B-26	F11	M21
3	4B-28	F10	L19
3	4B-30/CLK_OUT1	B11	L20
3	GNDIO3	GND	GND
3	4A-30	NC	M17
3	4A-28	NC	M22
3	4A-26	NC	K20
3	4A-24	NC	L18
3	4A-22	NC	L21
3	4A-20	NC	K19
3	4A-18	NC	L22
3	4A-16	NC	K17
3	4A-14	E13	K22
3	4A-12	B12	L17
3	GNDIO3	GND	GND
3	4A-10	E15	K21
3	4A-8	D15	K18
3	4A-6	NC	J17
3	4A-4	NC	J19
3	4A-2	D16	J22
3	4A-0	E12	J21
3	5B-0	NC	H19
3	5B-2	NC	H20
3	5B-4	NC	H17
3	5B-6	NC	H18
3	5B-8	NC	H22
3	5B-10	NC	H21
3	GNDIO3	GND	GND
3	5B-12	NC	G20
3	5B-14	NC	G22
3	5B-16	NC	G17
3	5B-18	NC	G21
3	5B-20	NC	F19
3	5B-22	NC	F20
3	5B-24	A16	F22
3	5B-26	B15	E22
3	5B-28	A15	E19
3	5B-30	D13	E20
3	5A-30	B14	D22
3	5A-28	B16	D21
3	GNDIO3	GND	GND
3	5A-26	C16	D20

Bank No.	Signal	256 fpBGA	484 fpBGA
3	5A-24	C15	C22
3	5A-22	D14	C18
3	5A-20	A14	C19
3	5A-18	C13	D17
3	5A-16	B13	C21
3	5A-14	NC	NC
3	5A-12	NC	NC
3	GNDIO3	GND	GND
3	5A-10	NC	NC
3	5A-8	NC	NC
3	5A-6	NC	B22
3	5A-4	NC	D18
3	5A-2	NC	B20
3	5A-0	NC	F17
3	5D-0	NC	B19
3	5D-2	NC	C17
3	GNDIO3	GND	GND
3	5D-4	NC	A21
3	5D-6	NC	D15
3	5D-8	NC	A20
3	5D-10	NC	C16
3	5D-12	NC	A19
3	5D-14	NC	F16
3	5D-16	NC	B16
3	5D-18	NC	D14
3	5D-20	NC	A18
3	5D-22	A13	F15
3	5D-24	A12	A17
3	5D-26	A11	B15
3	GNDIO3	GND	GND
3	5D-28	A10	A16
3	5D-30	C11	F14
3	5C-0	A9	C15
3	5C-2	D12	D13
3	5C-4	D11	E15
3	5C-6	B10	F13
3	5C-8	B9	B14
3	5C-10	E11	E13
3	5C-12/VREF3	A8	A15
3	5C-14	D10	D12
3	5C-16	E10	A14
3	5C-18	A7	B13
3	GNDIO3	GND	GND

ispMACH 5768VG Logic Signal Connections (Continued)

Bank No.	Signal	256 fpBGA	484 fpBGA
3	5C-20	C9	A13
3	5C-22	E9	B12
3	5C-24	D9	C13
3	5C-26	B8	A12
3	5C-28	A6	C12
3	5C-30	B7	A11
—	GCLK0	H4	P6
—	GCLK1	J4	R6
—	GCLK2	H14	P17
—	GCLK3	H13	P19
—	GOE0	J15	R18
—	GOE1	H15	R17
—	RESETB	J14	R19
—	TCK	J3	R3
—	TDI	H3	R2
—	TDO	J2	R4
—	TMS	H2	T1
—	TOE	J13	T18

Signal Configuration

ispMACH 5768VG and 51024VG 484-ball fpBGA

	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	
A	GND	I/O	I/O	I/O	I/O	I/O	I/O	I/O / VREF3	I/O	I/O	I/O	I/O	I/O	I/O / VREF0	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	A
B	I/O	VCC	I/O	I/O	VCC03	VCC	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	VCC	VCC00	I/O	I/O	VCC	I/O	B
C	I/O	I/O	GND	I/O	I/O	I/O	I/O	I/O	VCC	I/O	I/O	I/O	I/O	VCC	I/O	I/O	I/O	I/O	I/O	GND	I/O	I/O	C
D	I/O	I/O	I/O	GND	I/O	I/O	VCC03	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	VCC00	I/O	I/O	GND	I/O	I/O	I/O	D
E	I/O	VCC03	I/O	I/O	VCC	VCC03	GND	I/O	VCC03	I/O	I/O	I/O	I/O	VCC00	I/O	GND	VCC00	VCC	I/O	I/O	VCC00	I/O	E
F	I/O	VCC	I/O	I/O	VCC03	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	VCC00	I/O	I/O	VCC	I/O	F
G	I/O	I/O	I/O	VCC03	GND	I/O	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	I/O	GND	VCC00	I/O	I/O	I/O	G
H	I/O	I/O	I/O	I/O	I/O	I/O	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	I/O	I/O	I/O	I/O	I/O	I/O	H
J	I/O	I/O	VCC	I/O	VCC03	I/O	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	I/O	VCC00	I/O	VCC	I/O	I/O	J
K	I/O	I/O	I/O	I/O	I/O	I/O	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	I/O	I/O	I/O	I/O	I/O	I/O	K
L	I/O	I/O	I/O / CLK_OUT1	I/O	I/O	I/O	GNDP1	GND	GND	GND	GND	GND	GND	GND	GND	GND	VCCP0	GNDP0	I/O	I/O	I/O	I/O	L
M	I/O	I/O	I/O	I/O	I/O	I/O	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	I/O	I/O	I/O / PLL_RST0	I/O	I/O	I/O	M
N	I/O	I/O	I/O / PLL_RST1	I/O	VCCP1	I/O	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	I/O	I/O	I/O / PLL_FBK0	I/O	I/O	I/O / CLK_OUT0	N
P	I/O	I/O / PLL_FBK1	VCC	GCLK3	VCC02	GCLK2	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GCLK0	VCC01	VCCJ	VCC	I/O	I/O	P
R	I/O	I/O	I/O	RESETB	GOE0	GOE1	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GCLK1	I/O	TDO	TCK	TDI	I/O	R
T	I/O	I/O	I/O	GND	TOE	I/O	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	I/O	I/O	GND	I/O	I/O	TMS	T
U	I/O	VCC	I/O	I/O	VCC02	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	VCC01	I/O	I/O	VCC	I/O	U
V	I/O	I/O	I/O	I/O	I/O	VCC02	I/O	I/O	VCC02	I/O	I/O	I/O	I/O	VCC01	I/O	I/O	VCC01	I/O	I/O	I/O	I/O	I/O	V
W	I/O	I/O	I/O	I/O	I/O	I/O	GND	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	I/O	I/O	I/O	I/O	I/O	I/O	W
Y	I/O	I/O	VCC02	I/O	I/O	I/O	I/O	I/O	VCC	I/O	I/O	I/O	I/O	VCC	I/O	I/O	I/O	I/O	I/O	VCC01	I/O	I/O	Y
AA	I/O	VCC	I/O	I/O	I/O	VCC	I/O	I/O	I/O	I/O / VREF2	I/O	I/O	I/O / VREF1	I/O	I/O	I/O	VCC	I/O	I/O	I/O	VCC	NC ¹	AA
AB	GND	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	AB
	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	

ispMACH 5768VG and 51024VG

484BGA/51024VG

Bottom View

1. NCs are not to be connected to any active signals, VCC or GND.

Note: Ball A1 indicator dot on top side of package.

Signal Configuration

ispMACH 51024VG 676-ball fpBGA

	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1		
A	GND	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	NC ¹	NC ¹	NC ¹	NC ¹	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	A	
B	I/O	VCC	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	NC ¹	NC ¹	NC ¹	NC ¹	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	I/O	B	
C	I/O	I/O	GND	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	I/O	I/O/VREF0	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	I/O	I/O	C	
D	I/O	I/O	I/O	I/O	I/O	VCC	I/O	GND	I/O	VCC	I/O	VCC	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	VCC	I/O	VCC	I/O	GND	I/O	VCC	I/O	I/O	I/O	I/O	I/O	D	
E	I/O	I/O	I/O	I/O	VCC03	I/O	VCC03	I/O	VCC03	I/O	VCC03	I/O/VREF3	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	I/O	VCC00	I/O	VCC00	I/O	VCC00	I/O	VCC00	I/O	I/O	I/O	I/O	I/O	E
F	I/O	I/O	I/O	VCC	I/O	I/O	GND	I/O	GND	VCC03	GND	GND	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	GND	GND	VCC00	GND	I/O	GND	I/O	I/O	VCC	I/O	I/O	I/O	I/O	F
G	I/O	I/O	I/O	I/O	VCC03	GND																	GND	VCC00	I/O	I/O	I/O	I/O	G			
H	I/O	I/O	I/O	GND	I/O	I/O																	I/O	I/O	GND	I/O	I/O	I/O	H			
J	I/O	I/O	I/O	I/O	VCC03	GND																	GND	VCC00	I/O	I/O	I/O	I/O	J			
K	I/O	I/O	I/O	VCC	I/O	VCC03																	VCC00	I/O	VCC	I/O	I/O	I/O	K			
L	I/O	I/O	I/O	I/O	VCC03	GND																	GND	VCC00	I/O	I/O	I/O	I/O	L			
M	I/O	I/O/CLK_OUT1	I/O	VCC	I/O	GND																	GND	I/O	VCC	I/O	I/O/CLK_OUT0	I/O	M			
N	I/O	I/O	I/O	I/O	VCCP1	I/O																	I/O	I/O	I/O	I/O	I/O	I/O	N			
P	I/O	I/O	I/O	I/O	GCLK3	GNDP1																	I/O	VCCP0	I/O	I/O	I/O	I/O/PLL_RST0	P			
R	I/O	I/O	I/O/PLL_RST1	I/O/PLL_FBK1	GOE1	GCLK2																	GNDP0	GCLK0	I/O/PLL_FBK0	I/O	I/O	I/O	R			
T	I/O	I/O	I/O	I/O	GOE0	RESETB																	GCLK1	TDI	TMS	I/O	I/O	I/O	T			
U	I/O	I/O	I/O	I/O	TOE	I/O																	VCCJ	TCK	I/O	I/O	I/O	I/O	U			
V	I/O	I/O	I/O	I/O	I/O	I/O																	I/O	TDO	I/O	I/O	I/O	I/O	V			
W	I/O	I/O	I/O	VCC	I/O	GND																	GND	I/O	VCC	I/O	I/O	I/O	W			
Y	I/O	I/O	I/O	I/O	VCC02	GND																	GND	VCC01	I/O	I/O	I/O	I/O	Y			
AA	I/O	I/O	I/O	VCC	I/O	VCC02																	VCC01	I/O	VCC	I/O	I/O	I/O	AA			
AB	I/O	I/O	I/O	I/O	VCC02	GND																	GND	VCC01	I/O	I/O	I/O	I/O	AB			
AC	I/O	I/O	I/O	GND	I/O	I/O																	I/O	I/O	GND	I/O	I/O	I/O	AC			
AD	I/O	I/O	I/O	I/O	VCC02	GND																	GND	VCC01	I/O	I/O	I/O	I/O	AD			
AE	I/O	I/O	I/O	VCC	I/O	I/O	GND	I/O	GND	VCC02	GND	GND	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	GND	GND	VCC01	GND	I/O	GND	I/O	I/O	VCC	I/O	I/O	I/O	AE	
AF	I/O	I/O	I/O	I/O	VCC02	I/O	VCC02	I/O	VCC02	I/O	VCC02	I/O	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	I/O	VCC01	I/O	VCC01	I/O	VCC01	I/O	VCC01	I/O	I/O	I/O	I/O	AF	
AG	I/O	I/O	I/O	I/O	I/O	VCC	I/O	GND	I/O	VCC	I/O	VCC	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	VCC	I/O	VCC	I/O	GND	I/O	VCC	I/O	I/O	I/O	I/O	I/O	AG	
AH	I/O	I/O	GND	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	I/O	I/O	AH	
AJ	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O/VREF2	I/O	I/O	NC ¹	NC ¹	NC ¹	NC ¹	NC ¹	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	VCC	I/O	AJ
AK	GND	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	NC ¹	NC ¹	NC ¹	NC ¹	I/O	I/O	I/O	I/O/VREF1	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	I/O	GND	AK
	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1		

ispMACH 51024VG

Bottom View

ispMACH 51024VG

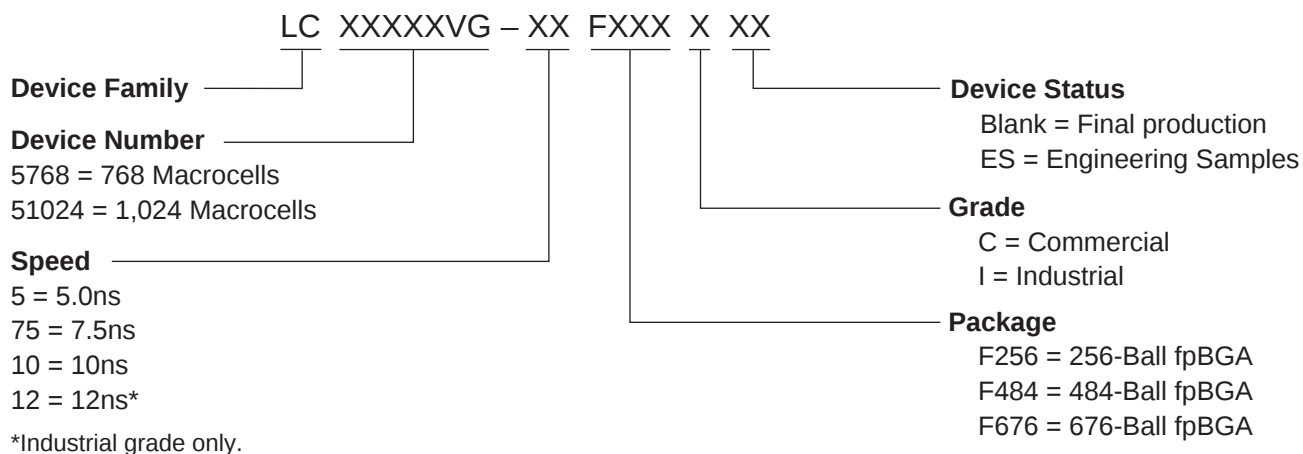
Bottom View

676BGA/51024VG

1. NCs are not to be connected to any active signals, VCC or GND.

Note: Ball A1 indicator dot on top side of package.

Part Number Description



0212/ispM5vg

Ordering Information

Commercial

Part Number	Package	Pin Count	Macrocells	Tpd	Voltage
LC51024VG-5F484C	fpBGA	484	1024	5	3.3
LC51024VG-75F484C	fpBGA	484	1024	7.5	3.3
LC51024VG-10F484C	fpBGA	484	1024	10	3.3
LC51024VG-5F676C	fpBGA	676	1024	5	3.3
LC51024VG-75F676C	fpBGA	676	1024	7.5	3.3
LC51024VG-10F676C	fpBGA	676	1024	10	3.3
LC5768VG-5F256C	fpBGA	256	768	5	3.3
LC5768VG-75F256C	fpBGA	256	768	7.5	3.3
LC5768VG-10F256C	fpBGA	256	768	10	3.3
LC5768VG-5F484C	fpBGA	484	768	5	3.3
LC5768VG-75F484C	fpBGA	484	768	7.5	3.3
LC5768VG-10F484C	fpBGA	484	768	10	3.3

Note: the ispMACH 5000VG family is dual-marked with both Commercial and Industrial grades. The Commercial speed grade is one speed grade faster (i.e. LC51024VG-75F484C) than the Industrial speed grade (i.e. LC51024VG-10F484I).